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[Proposal for a local heating driven spin current generator](http://dx.doi.org/10.1063/1.4826108)

Sun-Yong Hwang,^{1,2} Jong Soo Lim,^{2,3} Rosa López,^{2,4} Minchul Lee,⁵ and David Sánchez^{2,4} ¹Department of Physics, Pohang University of Science and Technology, Pohang 790-784, Korea ²Institut de Física Interdisciplinària i Sistemes Complexos IFISC (UIB-CSIC), E-07122 Palma de Mallorca, Spain

³School of Physics, Korea Institute for Advanced Study, Seoul 130-722, Korea

⁴Departament de Física, Universitat de les Illes Balears, E-07122 Palma de Mallorca, Spain
⁵Department of Applied Physics, College of Applied Science, Kyung Hee University, Vonein 5 Department of Applied Physics, College of Applied Science, Kyung Hee University, Yongin 446-701, Korea

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We propose a two-terminal spin-orbit interferometer with a hot molecule inserted in one of its arms to generate pure spin currents. Local heating is achieved by coupling the vibrational modes of the molecule to a third (phononic) reservoir. We show that this spin caloritronic effect is due to the combined influence of spin-dependent wave interference and inelastic scattering. Remarkably, the device converts heat flow into spin-polarized current even without applying any voltage or temperature difference to the electronic terminals. \odot 2013 AIP Publishing LLC. [\http://dx.doi.org/10.1063/1.4826108]

Recent experimental demonstrations of spin-polarized cur-rents using thermal gradients only^{[1,2](#page-2-0)} have fueled the interest in finding synergies between thermoelectricity and spintronics. Thus, the field of spin caloritronics³ seeks new functionalities that exploit the coupling of charge, spin, and energy degrees of freedom in nanostructures. Here we propose a molecule-based spin caloritronic device that extracts heat from a nearby phonon bath and transforms it into a spin current that flows out into coupled electronic reservoirs. Crucial to our setup is the presence of tunable spin-orbit interactions, which causes traveling electrons to acquire a phase that depends on its spin orientation within an Aharonov-Bohm-type interferometer.

Recent works predict that heat current can be converted into electric current in three-terminal thermoelectric nanode-vices either due to inelastic processes at a molecular bridge^{[4](#page-2-0)} or due to Coulomb coupling in interacting quantum dots.⁵ The generated charge current is determined by the temperature difference between the third terminal kept at an elevated temperature and the base temperature of the system. Further investigations include time-reversal symmetry breaking effects, 6 chaotic cavity heat engines, 7 and phonon-assisted instabilities.^{[8](#page-2-0)} The effect originates from a rectification of temperature fluctuations in the coupled unbiased conductor, similarly to the directed motion induced in the drag effect.^{[9](#page-2-0)} Importantly, unlike the pure electric case which requires four current-carrying terminals, in these thermoelectric effects it suffices to couple a third energy-supplying subsystem (electronic or phononic).

Our proposal considers an Aharonov-Bohm (AB) ring connected to two normal electronic reservoirs and a molecule embedded in one arm of the ring, see Fig. [1](#page-1-0). For definiteness, the molecule is assumed to have a single level active for transport. The system is subjected to Rashba spinorbit interaction arising in inversion asymmetric potentials. This configuration has been shown to give rise to local spin polarizations,^{[10](#page-2-0)} spin separation,^{[11](#page-2-0)} and pure spin currents.^{[12](#page-2-0)} Furthermore, this is a useful setup to analyze the competition between spin randomizing Rashba interactions and many-body spin singlets arising from Kondo correlations.^{[13,14](#page-2-0)} These works require small voltage biases applied to the Fermi reservoirs. In contrast, our device operates in the entire absence of electric or thermal gradients applied to the leads, but is instead based on a hot phonon field locally coupled to the embedded molecule.

The model Hamiltonian for our device, $H = H_C + H_M$ $H + H_T$, consists of three parts: $H_C = \sum_{\ell=L/R,k,\sigma} \varepsilon_{k\sigma} c_{\ell k\sigma}^{\dagger}$ is the Hamiltonian of two normal left (L) and right (R) electronic reservoirs, $\mathcal{H}_M = \sum_{\sigma} E_d d_{\sigma}^{\dagger} d_{\sigma} + \hbar \omega_0 a^{\dagger} a + \lambda (a + a^{\dagger})$ $\sum_{\sigma} d_{\sigma}^{\dagger} d_{\sigma}$ describes the embedded molecule with level E_{d} coupled to a phonon bath with an excitation frequency ω_0 and coupling strength λ , and $\mathcal{H}_T = \sum_{\ell,k,\sigma} (V_{\ell}c_{ik\sigma}^{\dagger}d_{\sigma} + \text{H.c.})$ $+\sum_{k,p,\sigma}(We^{i\varphi}\sigma_{Rp\sigma}^{\dagger}C_{Lk\sigma}+H.c.)$ accounts for electron tunneling between the molecule and the reservoirs. Here, $c_{\ell k\sigma} (c_{\ell k\sigma}^{\dagger})$ are fermionic annihilation (creation) operators for electrons with wave vector k and spin σ in lead $\ell = L/R$ and $d_{\sigma}(d_{\sigma}^{\dagger})$ represent electrons at the molecule site and $a(a^{\dagger})$ denotes the bosonic annihilation (creation) operator. V_{ℓ} is the probability amplitude for an electron transfer between the molecule and the electronic reservoirs whereas W describes direct tunneling between electronic reservoirs. The effect of Rashba spinorbit interaction acting upon the molecule is embodied in the phase factor^{[10–14](#page-2-0)} $\varphi_{\sigma} = \sigma \varphi$, where $\varphi = \alpha_R l$ (α_R is the Rashba strength and l the size of the molecule) and $\sigma = +(-)$ for spins up (down).

We consider thermoelectric effects in the linear response regime. Thus, we expand the electrochemical potential and temperature in each electronic reservoir around the equilibrium state defined with common chemical potential μ and base temperature T. Then, $\mu_{\ell\sigma} = \mu + \Delta\mu_{\ell\sigma}$ and $T_{L/R} = T \pm \Delta T/2$; similarly, $T_P = T + \Delta T_P$ for the phonon bath. Using $\Delta \mu_{\sigma}$ $= \mu_{L\sigma} - \mu_{R\sigma}$, we define the charge and spin voltage biases $e\Delta V = (\Delta\mu_{\uparrow} + \Delta\mu_{\downarrow})/2$ and $e\Delta V_s = (\Delta\mu_{\uparrow} - \Delta\mu_{\downarrow})/2$, respectively.¹⁵ Hence, the spin-resolved current is

$$
I_{\sigma} = G(\varphi_{\sigma})\Delta V + \sigma G(\varphi_{\sigma})\Delta V_s + L(\varphi_{\sigma})\frac{\Delta T}{T} + X_P(\varphi_{\sigma})\frac{\Delta T_P}{T}.
$$
\n(1)

The transport coefficient G is the linear conductance in response to a charge or spin voltage shift. L is the thermoelectric response due to a temperature difference applied to

FIG. 1. Schematics of the setup. A molecule or quantum dot with a single level E_d is embedded in an Aharonov-Bohm ring coupled to two Fermi reservoirs (L and R) with electrochemical potentials $\mu_{L(R)}$ and temperatures $T_{L(R)}$. A spin-dependent phase φ_{σ} originates from spin-orbit Rashba interactions, generally leading to spin-dependent chemical potentials, $\mu_{\ell\sigma}$. Our device is influenced by the presence of a bosonic bath described by the Bose-Einstein distribution function N_{ph} with temperature T_P .

the electronic leads. Finally, X_P describes phonon-assisted transport owing to possible temperature differences between the bosonic bath and the system. We remark that local phonon heating effects have been investigated in electronic mo-lecular systems.^{[16,17](#page-2-0)}

Importantly, the transport coefficients in Eq. [\(1\)](#page-0-0) have elastic and inelastic contributions: $G = G_{el} + G_P$ and $L = L_{el}$ $+ L_P$. Expressions for G_{el} and L_{el} can be found in Ref. [6](#page-2-0) with the replacement $\varphi_{AB} \rightarrow \varphi_{\sigma}$. We here prefer to focus on the inelastic contribution originated from electron-phonon (e-ph) coupling since it is precisely the combined effect of inelastic scattering and spin-orbit interaction which establishes the operating principle of our proposed device. Within the none-quilibrium Green function approach,^{[18](#page-2-0)} we find $G_P(\varphi_\sigma) =$ quinorium Sicen function approach, we may $\partial P(\phi_{\sigma}) = (2\lambda^2 e^2/h) \int d\varepsilon B(\varepsilon, \varphi_{\sigma}) M_0(\varepsilon, \varphi_{\sigma})$, where $B(\varepsilon, \varphi_{\sigma}) = (N_T/k_B T)$ $\tilde{\Gamma}(\varepsilon_{+})\tilde{\Gamma}(\varepsilon_{-})|\mathscr{G}_{\sigma,\sigma}^{r}(\varepsilon_{+})\mathscr{G}_{\sigma,\sigma}^{r}(\varepsilon_{-})|^{2}(1-f_{0}(\varepsilon_{+}))f_{0}(\varepsilon_{-})$ and $M_0(\varepsilon, \varphi_\sigma) \equiv 1 - \mathcal{A}(\varepsilon_+) \mathcal{A}(\varepsilon_-) + \sqrt{\mathcal{T}(\varepsilon_+) \mathcal{T}(\varepsilon_-)} \sin^2(\varphi_\sigma)$ with $\varepsilon_{\pm} = \varepsilon \pm \hbar \omega_0/2$, the Fermi distribution function $f_0(\varepsilon)$ $=(e^{(\varepsilon-\mu)/k_BT}+1)^{-1}$, and the Bose occupation factor $N_T = (e^{\hbar \omega_0 / k_B T} - 1)^{-1}$, both evaluated at equilibrium. Here, $\Gamma(\varepsilon) = (\Gamma_L(\varepsilon) + \Gamma_R(\varepsilon))/(1 + \xi(\varepsilon))$ is the (renormalized) total resonance width, where $\Gamma_{\ell}(\varepsilon) = \pi \rho_{\ell}(\varepsilon) V_{\ell}^2$ and $\xi(\varepsilon) = \pi^2 \rho_L$ $(\varepsilon)\rho_R(\varepsilon)W^2$ is the direct tunneling coupling, with $\rho_\ell(\varepsilon)$ the l-lead density of states. The retarded Green's function in the absence of e-ph coupling is given by $\mathscr{G}^r_{\sigma,\sigma}(\varepsilon) = (\varepsilon - \varepsilon_d + i\tilde{\Gamma})$ absence of e-ph coupling is given by $\mathcal{B}_{\sigma,\sigma}(k) = (k - k_d + lT)$
 $+\tilde{\Gamma}\sqrt{\alpha \xi} \cos \varphi_\sigma^{-1}$ with $\alpha(\epsilon) = 4\Gamma_L \Gamma_R/(\Gamma_L + \Gamma_R)^2$. We have defined the functions $\mathcal{A}(\varepsilon) = [(\Gamma_L - \Gamma_R)/(\Gamma_L + \Gamma_R)][(1 - \xi)]$ $(1+\xi)$ and $\mathcal{T}(\varepsilon) = 4\alpha\xi/(1+\xi)^2$. The thermopower inelastic term can be cast in the form $L_P(\varphi_\sigma) = (2\lambda^2 e/h) \int d\varepsilon B(\varepsilon, \varphi_\sigma)$ $[(\varepsilon - \mu)M_0(\underline{\varepsilon}, \varphi_\sigma) + (\hbar\omega_0/2)M_1(\varepsilon, \varphi_\sigma)], \text{ where } M_1(\varepsilon, \varphi_\sigma)$ $\equiv [\mathcal{A}(\epsilon_+) \sqrt{\mathcal{T}(\epsilon_-)} - \mathcal{A}(\epsilon_-) \sqrt{\mathcal{T}(\epsilon_+)}] \sin \varphi_\sigma.$ Finally, the phonon assisted current contribution is $X_P(\varphi_{\sigma}) = (2\lambda^2 e/h)$ honon assisted earlier contribution is $\Lambda_P(\psi_\sigma) = (2\lambda \epsilon_P n)$
 $\hbar \omega_0 \int d\varepsilon B(\varepsilon, \varphi_\sigma) M_2(\varepsilon, \varphi_\sigma)$ with $M_2(\varepsilon, \varphi_\sigma) \equiv [\mathcal{A}(\varepsilon_-) - \mathcal{A}(\varepsilon_+)]$ $\mu = \left[\sqrt{T(\epsilon_+) - \sqrt{T(\epsilon_-)}}\right] \sin \varphi_{\sigma}$.

In the wide-band limit, ρ_{ℓ} is energy independent. Then, $T(\varepsilon)$ and $\mathcal{A}(\varepsilon)$ become constants and we find $X_P(\varphi_{\sigma}) = 0$, i.e., the spin current I_{σ} is insensitive to changes in T_{P} . Interestingly, for the general case of energy-dependent densities of states our model predicts, quite generally, a spindependent flow generated by nonzero ΔT_P . To see this, let us analyze the charge $I_c = I_{\uparrow} + I_{\downarrow}$ current,

$$
I_c = [G(\varphi_{\uparrow}) + G(\varphi_{\downarrow})]\Delta V + [G(\varphi_{\uparrow}) - G(\varphi_{\downarrow})]\Delta V_s
$$

+
$$
[L(\varphi_{\uparrow}) + L(\varphi_{\downarrow})]\frac{\Delta T}{T} + [X_P(\varphi_{\uparrow}) + X_P(\varphi_{\downarrow})]\frac{\Delta T_P}{T}, (2)
$$

and the spin $I_s = I_{\uparrow} - I_{\downarrow}$ current,

$$
I_s = [G(\varphi_\uparrow) - G(\varphi_\downarrow)]\Delta V + [G(\varphi_\uparrow) + G(\varphi_\downarrow)]\Delta V_s
$$

+
$$
[L(\varphi_\uparrow) - L(\varphi_\downarrow)]\frac{\Delta T}{T} + [X_P(\varphi_\uparrow) - X_P(\varphi_\downarrow)]\frac{\Delta T_P}{T}.
$$
 (3)

In order to examine the possibility of generating pure spin current, i.e., $I_c = 0$ and $I_s \neq 0$, only via local heating $(\Delta T_P \neq 0)$ we set $\Delta T = 0$ henceforth. Due to symmetry considerations, we have $G(\varphi_1) = G(\varphi_1) \equiv G(\varphi)$. In addition, for symmetric couplings $(\Gamma_L = \Gamma_R)$ we find $X_P(\varphi) = -X_P(\varphi) \equiv X_P(\varphi)$. Hence, Eqs. (2) and (3) reduce to

$$
I_c = 2G(\varphi)\Delta V,\tag{4}
$$

$$
I_s = 2G(\varphi)\Delta V_s + 2X_P(\varphi)\frac{\Delta T_P}{T}.
$$
 (5)

This particularly simple result is central to our proposal. When no dc voltage is applied $(\Delta V = 0)$, the charge current I_c vanishes and just a pure spin current remains. Furthermore, when the spin relaxation time in the reservoirs is very short, 19 we can neglect the term proportional to the spin bias ΔV_s and thus I_s is uniquely determined by the temperature difference between the phonon bath and the system. In general, our thermomagnetic device produces spinpolarized currents from temperature differences only.

For realistic systems, lead couplings can be asymmetric and we then obtain nonvanishing charge currents. However, this finite charge current can be cancelled by applying a compensating bias voltage across the system. A similar compensation effect has been proposed for a two-terminal quantum dot system. 20 The difference is that we heat up the molecule using local phonon coupling and allow for (Rashba) electric fields while Ref. [20](#page-2-0) uses Zeeman magnetic fields. Thus, our proposed device is an all-electrical setup.

FIG. 2. Normalized spin current versus the Rashba phase φ for (a) different phonon frequencies ω_0 at fixed direct tunnel coupling $\xi = 0.4$ and (b) different values of ξ for $\omega_0 = 0.4$. Parameters: $\lambda = 0.8$, $T = 0.1$, $\Delta T_P = 0.05$, $E_d = 0.8$, and bandwidth $D = 10$ with a semielliptic density of states $\rho(\varepsilon) = \sqrt{1 - 4(\varepsilon/D)^2}$. Here, energies are given in units of Γ and the current unit is $I_0 = e\omega_0 \lambda^2/\Gamma^2$.

FIG. 3. Normalized spin current versus the energy level position E_d for (a) different phonon frequency ω_0 at fixed direct tunnel coupling $\xi = 0.4$ and (b) different values of ξ for $\omega_0 = 0.4$. Parameters are taken as in Fig. [2](#page-1-0) with a fixed Rashba phase $\varphi = 0.35\pi$ near which the maximum spin current amplitude occurs.

Figures [2](#page-1-0) and 3 display the spin currents as a function of the Rashba phase φ and the molecular energy level E_d for various values of the phonon frequency ω_0 and direct tunneling strength ξ . Figure [2](#page-1-0) shows oscillations of the spin current when φ changes from 0 to 2π . At fixed temperature, the number of phonons decreases when ω_0 grows, yielding lower spin currents as shown in Fig. $2(a)$. In Fig. $2(b)$, we observe a weak dependence of the spin current amplitude on ξ . This is a nice property—the generated spin polarization is robust against unintentional variations of the background transmission. Figure 3 illustrates the gate dependence of I_s at a fixed Rashba phase. We also find that the current amplitude enhances as ω_0 decreases. Spin currents are maximized for specific positions of the molecular level: $E_d = -0.25\Gamma$ and $E_d = 0.75\Gamma$. Moreover, the level positions at which I_s is maximal depends weakly on ω_0 . Finally, Fig. 3(b) presents small variation of the spin current when ξ varies substantially, in agreement with the robustness discussed above.

In prototypical molecular transistors, vibrational frequencies are found to be of the order of THz for C_{60} (Ref. 21) and carbon nanotubes. 22 These systems are most suitable to test our predictions due to their intrinsic spin-orbit coupling.²³ We estimate from Figs. [2](#page-1-0) and 3 that the achievable spin currents are of the order of $I_s \sim 1 \text{ pA}$ for $\Gamma = \lambda = 1 \text{ meV}, \omega_0 =$ 1 THz, $T = 1$ K, and $\Delta T_P = 0.5$ K. A similar setup also yields currents of the order of 1 pA .⁵ This current range is small but can be detected within present techniques.²⁴

In summary, we have proposed a spin current generator by locally heating a molecule embedded in a spin-orbit interferometer. Our device works even in the absence of voltage and temperature bias applied to the electronic terminals. Importantly, our heat-to-spin current mechanism is independent of magnetic couplings to external reservoirs, in contrast to recent proposals which emphasize interactions with ferromagnetic leads. 25 We have found that optimal spin polarization can be determined by adjusting the Rashba spinorbit coupling and the energy level of the molecule. Our results are relevant in view of recent developments in the field of spin caloritronics. Analogous setups could be envisaged where spin is replaced with orbital (pseudospin) degrees of freedom.²⁶

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